

FGW40N120VD

Discrete IGBT

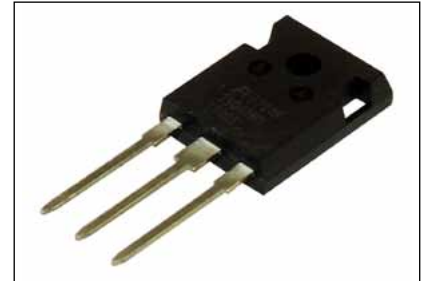
Discrete IGBT (High-Speed V series) 1200V / 40A

■ Features

- Low power loss
- Low switching surge and noise
- High reliability, high ruggedness (RBSOA, SCSOA etc.)

■ Applications

- Inverter for Motor drive
- AC and DC Servo drive amplifier
- Uninterruptible power supply



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at T_c=25°C unless otherwise specified)

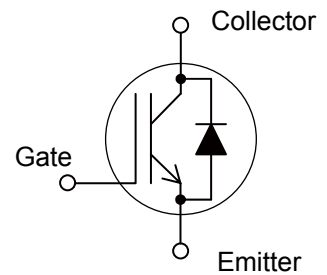
Items	Symbols	Characteristics	Units	Remarks
Collector-Emitter voltage	V _{CEs}	1200	V	
Gate-Emitter voltage	V _{GES}	±20	V	
DC Collector Current	I _{C@25}	63	A	T _c =25°C, T _j =150°C
	I _{C@100}	40	A	T _c =100°C, T _j =150°C
Pulsed Collector Current	I _{CP}	80	A	Note *1
Turn-Off Safe Operating Area	-	80	A	V _{CE} ≤1200V, T _j ≤175°C
Diode Forward Current	I _{F@25}	58	A	
	I _{F@100}	30	A	
Diode Pulsed Current	I _{FP}	80	A	Note *1
Short Circuit Withstand Time	t _{sc}	10	μs	V _{CE} ≤640V, V _{GE} =15V T _j ≤150°C
IGBT Max. Power Dissipation	P _{D_IGBT}	340	W	T _c =25°C
FWD Max. Power Dissipation	P _{D_FWD}	220	W	T _c =25°C
Operating Junction Temperature	T _j	-40~+175	°C	
Storage Temperature	T _{stg}	-55~+175	°C	

Note *1 : Pulse width limited by T_{jmax}.

● Electrical characteristics (at T_j= 25°C unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Unit
			min.	typ.	max.	
Collector-Emitter Breakdown Voltage	V _{BR(ICES)}	I _C = 50μA, V _{GE} = 0V	1200	-	-	V
Zero Gate Voltage Collector Current	I _{CEs}	V _{CE} = 1200V, V _{GE} = 0V	-	-	250	μA
		T _j =25°C	-	-	2	mA
		T _j =175°C	-	-	200	nA
Gate-Emitter Leakage Current	I _{GES}	V _{CE} = 0V, V _{GE} = ±20V	-	-	7.0	V
Gate-Emitter Threshold Voltage	V _{GE(th)}	V _{CE} = +20V, I _C = 40mA	6.0	6.5	7.0	V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	V _{GE} = +15V, I _C = 40A	-	1.85	2.4	V
		T _j =25°C	-	2.4	-	
		T _j =175°C	-	2.4	-	
Input Capacitance	C _{ies}	V _{CE} =25V	-	2230	-	pF
Output Capacitance	C _{oes}	V _{GE} =0V	-	135	-	
Reverse Transfer Capacitance	C _{res}	f=1MHz	-	105	-	
Gate Charge	Q _G	V _{CC} = 600V I _C = 40A V _{GE} = 15V	-	320	-	nC
Turn-On Delay Time	t _{d(on)}	T _j = 25°C	-	38	-	ns
Rise Time	t _r	V _{CC} = 600V	-	75	-	
Turn-Off Delay Time	t _{d(off)}	I _C = 40A	-	310	-	
Fall Time	t _f	V _{GE} = 15V	-	55	-	
Turn-On Energy	E _{on}	R _G = 10Ω	-	4.3	-	mJ
Turn-Off Energy	E _{off}	L = 500μH Energy loss include "tail" and FWD reverse recovery.	-	2.2	-	
Turn-On Delay Time	t _{d(on)}	T _j = 175°C	-	38	-	ns
Rise Time	t _r	V _{CC} = 600V	-	68	-	
Turn-Off Delay Time	t _{d(off)}	I _C = 40A	-	360	-	
Fall Time	t _f	V _{GE} = 15V	-	85	-	
Turn-On Energy	E _{on}	R _G = 10Ω	-	6.5	-	mJ
Turn-Off Energy	E _{off}	L = 500μH Energy loss include "tail" and FWD reverse recovery.	-	3.8	-	
Forward Voltage Drop	V _F	I _F =30A	-	1.7	2.21	V
		T _j =25°C	-	1.8	-	V
		T _j =175°C	-	1.8	-	
Diode Reverse Recovery Time	t _{rr1}	V _{CC} =30V I _F = 3.0A -di _F /dt=200A/μs	-	79	103	ns
Diode Reverse Recovery Time	t _{rr2}	V _{CC} =600V I _F =30A	-	0.33	-	μs
Diode Reverse Recovery Charge	Q _{rr}	-di _F /dt=200A/μs T _j =25°C	-	1.45	-	μC

■ Equivalent circuit



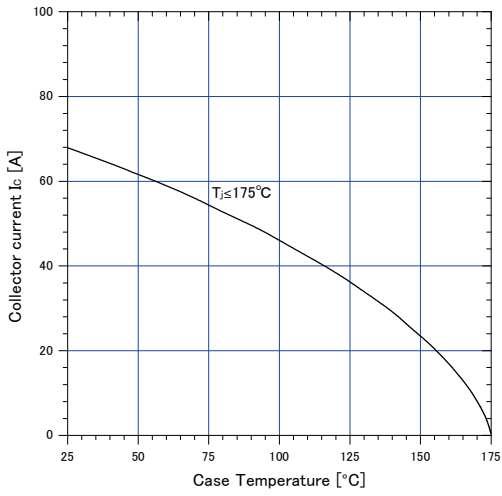
Items	Symbols	Conditions	Characteristics			Unit
			min.	typ.	max.	
Diode Reverse Recovery Time	t_{rr2}	$V_{CC}=600V$ $I_F=30A$	-	0.75	-	μs
Diode Reverse Recovery Charge	Q_{rr}	$-di_F/dt=200A/\mu s$ $T_j=175^\circ C$	-	4.30	-	μC

● Thermal resistance

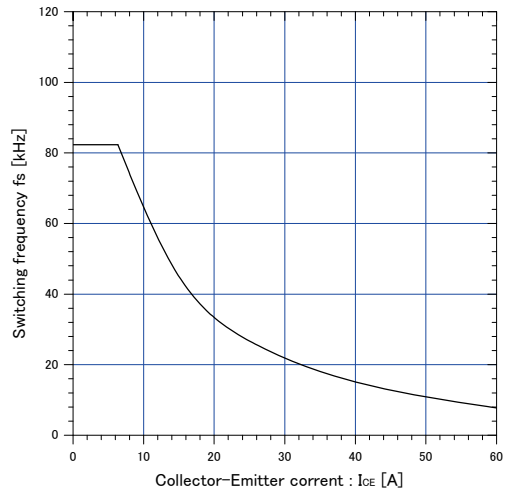
Items	Symbols	Characteristics			Unit
		min.	typ.	max.	
Thermal Resistance, Junction-Ambient	$R_{th(j-a)}$	-	-	50	$^\circ C/W$
Thermal Resistance, IGBT Junction to Case	$R_{th(j-c)}_{IGBT}$	-	-	0.439	
Thermal Resistance, FWD Junction to Case	$R_{th(j-c)}_{FWD}$	-	-	0.676	

■ Characteristics (Representative)

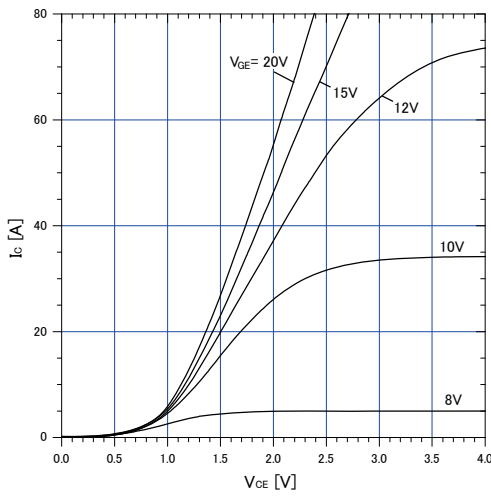
Graph.1
DC Collector Current vs T_c
 $V_{GE} \geq +15V, T_j \leq 175^\circ C$



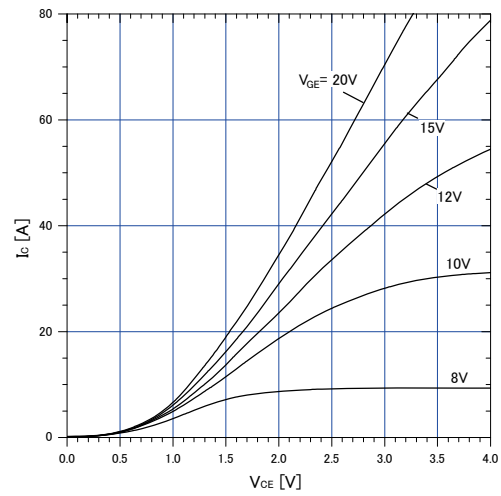
Graph.2
Collector Current vs. switching frequency
 $V_{GE} = +15V, T_c \leq 175^\circ C, V_{CE} = 600V, D = 0.5, R_g = 10\Omega, T_c = 100^\circ C$



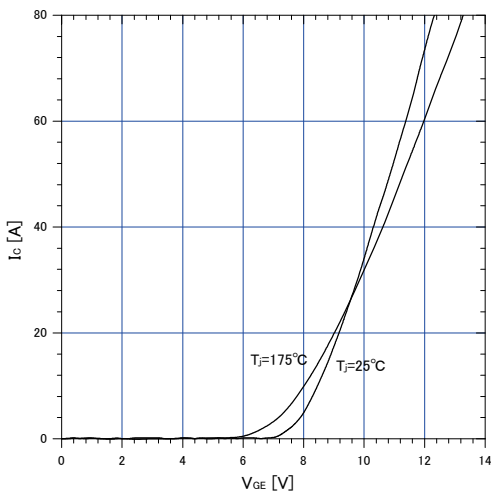
Graph.3
Typical Output Characteristics ($V_{CE} - I_c$)
 $T_j = 25^\circ C$



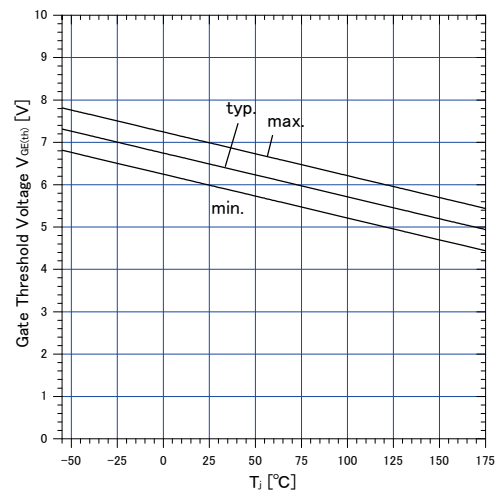
Graph.4
Typical Output Characteristics ($V_{CE} - I_c$)
 $T_j = 175^\circ C$



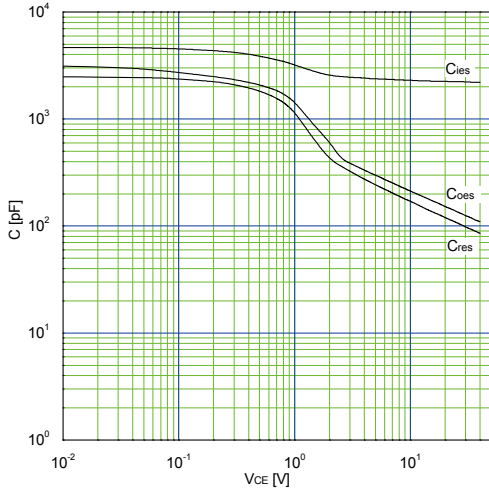
Graph.5
Typical Transfer Characteristics
 $V_{GE} = +15V$



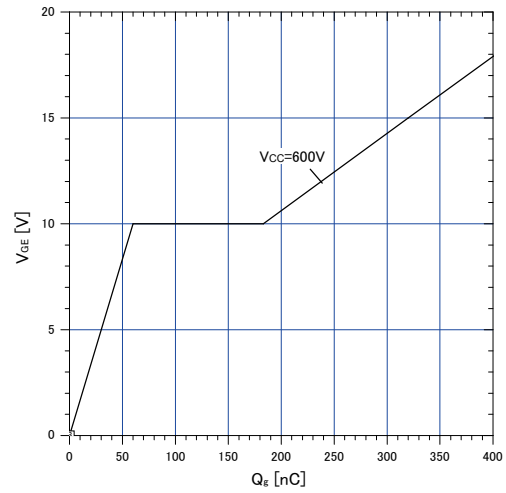
Graph.6
Gate Threshold Voltage vs. T_j
 $I_c = 40mA, V_{CE} = 20V$



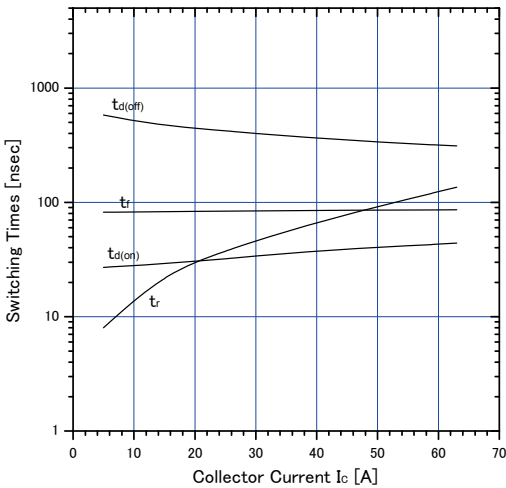
Graph.7
 Typical Capacitance
 $V_{GE}=0V, f=1MHz, T_j=25^\circ C$



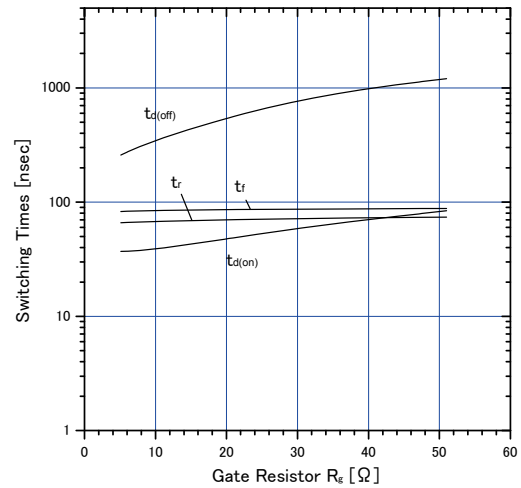
Graph.8
 Typical Gate Charge
 $V_{CC}=600V, I_c=40A, T_j=25^\circ C$



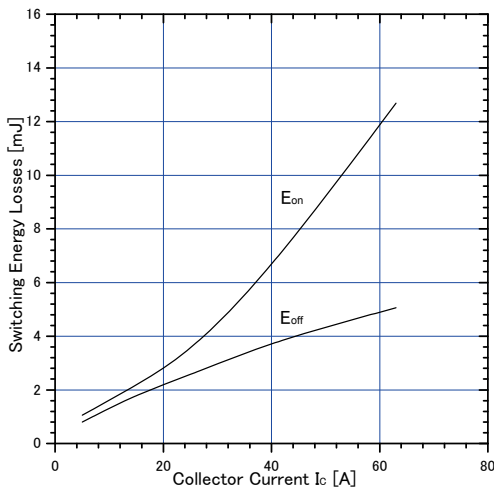
Graph.9
 Typical switching time vs. I_c
 $T_j=175^\circ C, V_{CC}=600V, L=500\mu H$
 $V_{GE}=15V, R_G=10\Omega$



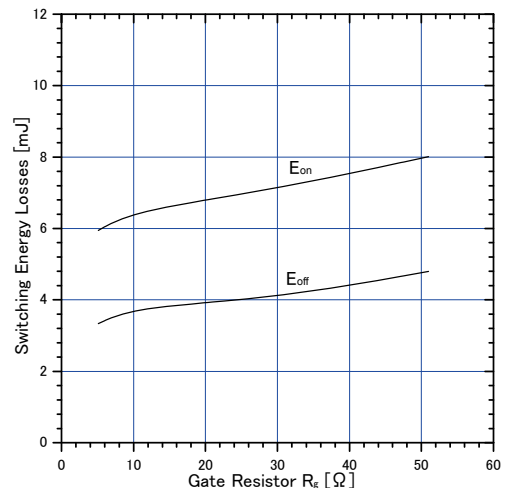
Graph.10
 Typical switching time vs. R_G
 $T_j=175^\circ C, V_{CC}=600V, I_c=40A, L=500\mu H$
 $V_{GE}=15V$



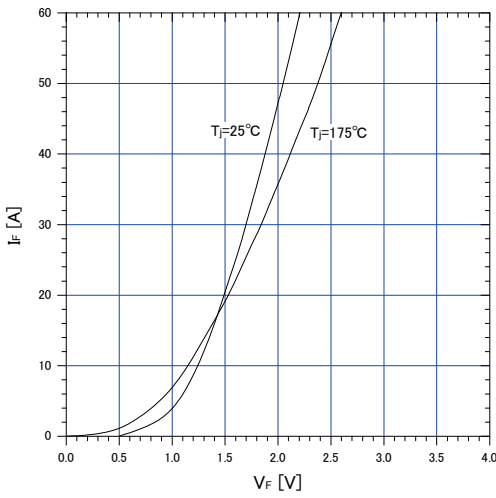
Graph.11
 Typical switching losses vs. I_c
 $T_j=175^\circ C, V_{CC}=600V, L=500\mu H$
 $V_{GE}=15V, R_G=10\Omega$



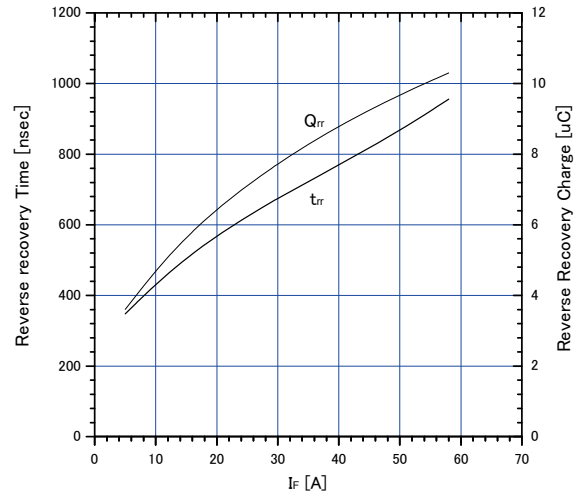
Graph.12
 Typical switching losses vs. R_G
 $T_j=175^\circ C, V_{CC}=600V, I_c=40A, L=500\mu H$
 $V_{GE}=15V$



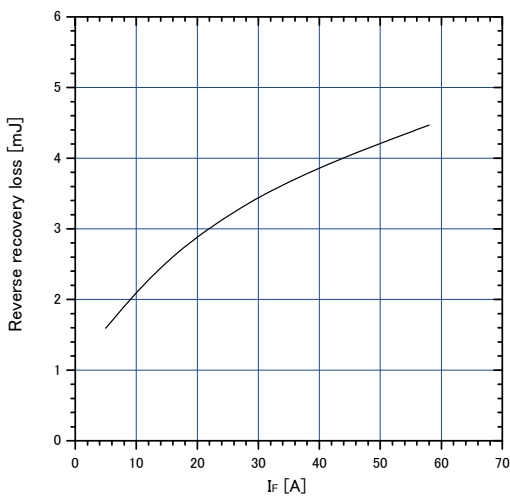
Graph.13
FWD Forward voltage drop (V_F-I_F)



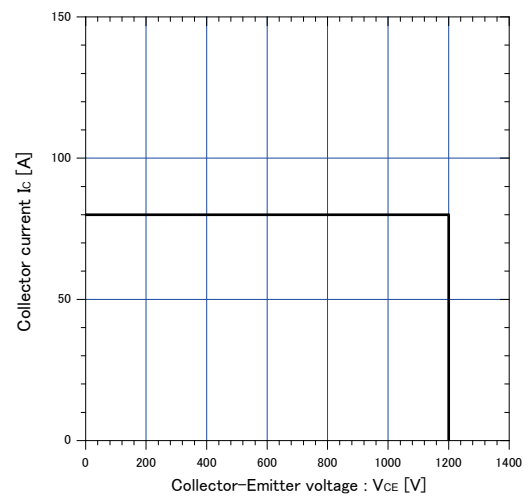
Graph.14
Typical reverse recovery characteristics vs. I_F
 $T_J=175^\circ\text{C}$, $V_{CC}=600\text{V}$, $L=500\mu\text{H}$,
 $V_{GE}=15\text{V}$, $R_G=10\Omega$



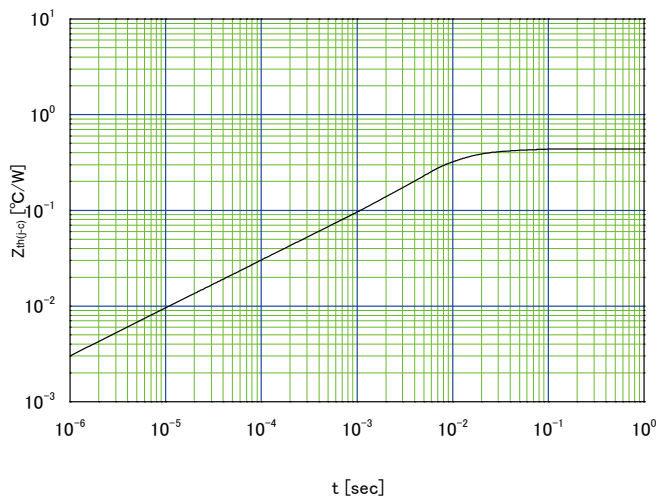
Graph.15
Typical reverse recovery loss vs. I_F
 $T_J=175^\circ\text{C}$, $V_{CC}=600\text{V}$, $L=500\mu\text{H}$
 $V_{GE}=15\text{V}$, $R_G=10\Omega$



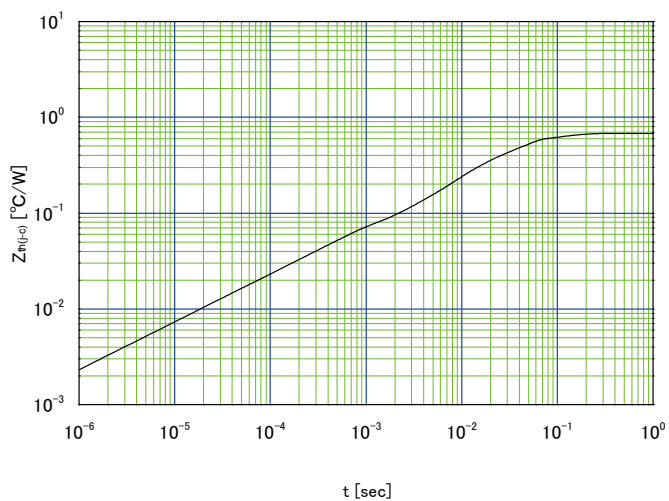
Graph.16
Reverse biased Safe Operating Area
 $T_J \leq 175^\circ\text{C}$, $V_{GE}=+15\text{V}/0\text{V}$, $R_G=10\Omega$



Graph.17
Transient thermal resistance of IGBT

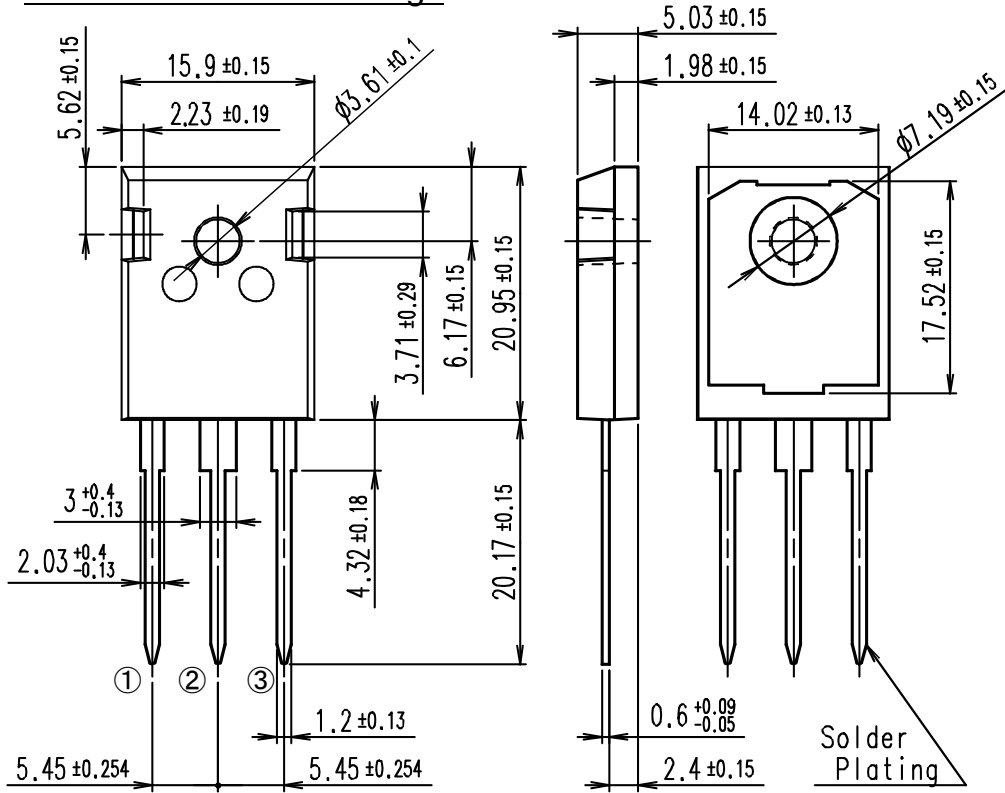


Graph.18
Transient thermal resistance of FWD



■ Outline Drawings, mm

Outview : TO-247 Package



CONNECTION

- ① GATE
- ② COLLECTOR
- ③ EMITTER

DIMENSIONS ARE IN MILLIMETERS.

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 - Electrical home appliances
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